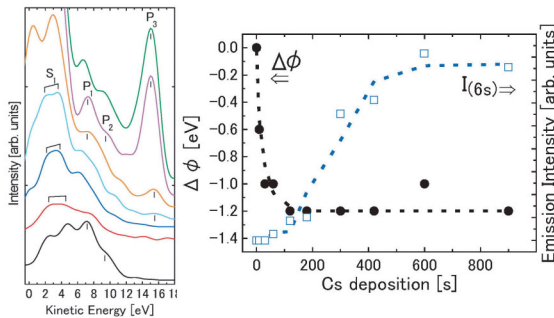
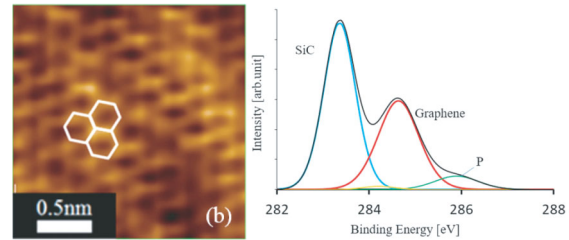


ホームページ : <http://www.sssj.org/ejsnt> 電子メール : ejssnt@sssj.org
J-Stage アーカイブ : <http://www.jstage.jst.go.jp/browse/ejsnt/>

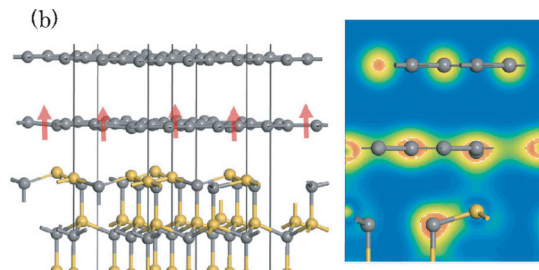
Cs吸着によるSiC結晶表面の酸化促進
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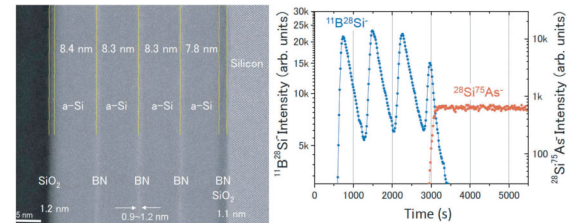
Junko Ishii, Yasuhiro Miyawaki, Naoya Tsuboi, Tomonori Ikari, Masamichi Naitoh



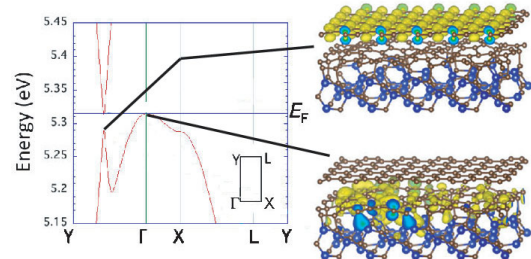
バッファ層を含めたグラフェンの電子状態
First-Principles Calculation Study of Epitaxial Graphene Layer on 4H-SiC (0001) Surface
(Conference -ALC '15) *Vol. 14, pp. 107-112 (April 2, 2016)*
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